

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

2SK4171

FEATURES

- Drain Current : I_D= 100A@ T_C=25℃
- Drain Source Voltage : V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 7.2m Ω (Max) @ V_{GS}= 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

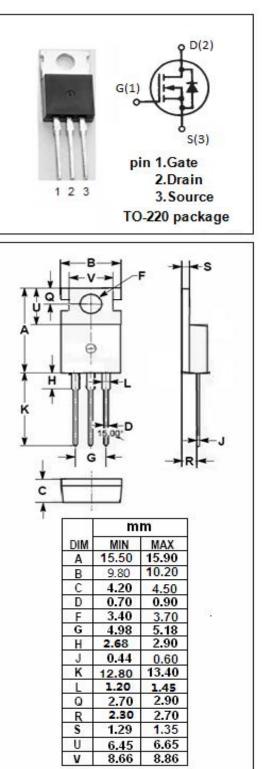
· motor drive, DC-DC converter, power switch and solenoid drive.

| ADSOLU | | | |
|------------------|-------------------------------------------|---------|------|
| SYMBOL | PARAMETER | VALUE | UNIT |
| V _{DSS} | Drain-Source Voltage | 60 | V |
| V _{GS} | Gate-Source Voltage-Continuous ±20 | | V |
| ID | Drain Current-Continuous | 100 | А |
| I _{DM} | Drain Current-Single Pluse | 400 | А |
| P _D | otal Dissipation @T _c =25°C 75 | | W |
| TJ | Max. Operating Junction Temperature | -55~150 | °C |
| T _{stg} | Storage Temperature | -55~150 | °C |

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | PARAMETER MAX | | |
|---------------------|--------------------------------------|---------------|------|--|
| R _{th j-c} | Thermal Resistance, Junction to Case | 1.67 | °C/W | |





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | МАХ | UNIT |
|----------------------|---------------------------------|-------------------------------------------------------------------------------------------|-----|-------------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 1.0mA | 60 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = 10V; I _D = 1.0mA | 1.2 | 2.6 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 50A V _{GS} = 4V; I _D = 50A | | 7.2 10.5 | mΩ |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±16V;V _{DS} =0 | | ±10 | uA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 60V; V _{GS} = 0 | | 1.0 | uA |
| V _{SD} | Forward On-Voltage | I _S = 100A; V _{GS} = 0 | | 1.2 | V |

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